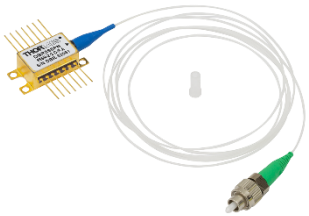
895 nm, 12 mW DBR Butterfly Laser with Isolator, PM Fiber



DBR895PN

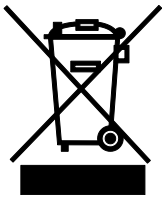
Description

Thorlabs' DBR895PN Distributed Bragg Reflector (DBR) laser is a single-frequency laser diode that is well-suited for a low-noise pump source for Cesium atomic clocks, second harmonic generation, and time-resolved fluorescence spectroscopy. The DBR895PN includes an integrated optical isolator, thermoelectric cooler (TEC), thermistor, and monitor photodiode. It is packaged in a 14-pin butterfly package with PM780-HP polarization-maintaining optical fiber and an FC/APC connector with the connector key aligned to the slow axis of the fiber.

Specifications

DBR895PN[a]				
	Symbol	**Min**	**Typical**	**Max**
Center Wavelength	λ_C	893 nm	895 nm	897 nm
Laser Linewidth	Δv	-	1 MHz	-
Output Power CW @ I_{OP}	P_{OP}	10 mW	12 mW	-
Operating Current	I_{OP}	-	300 mA	
Mode-Hop-Free Range[b]	$\Delta I_{Mode\text{-}Hop\text{-}Free}$	20 mA	-	-
SMSR in Mode-Hop-Free Range[c]	SMSR	30 dB	50 dB	-
30 dB BW in Mode-Hop-Free Range[c]	30 dB BW	-	-	0.3 nm
Threshold Current	I_{TH}	-	60 mA	-
Forward Voltage	V_F	-	2.0 V	2.5 V
Slope Efficiency	$\Delta P/\Delta I$	0.04 W/A	0.05 W/A	-
Current Tuning	$\Delta\lambda/\Delta I$	-	0.002 nm/mA	-
Temperature Tuning	$\Delta\lambda/\Delta T$	-	0.06 nm/°C	-
Monitor Diode Responsivity	I_{MON}/P	-	40 µA/mW	-
Polarization Extinction Ratio[d]	r_{ex}	-	16 dB	-
Internal Isolation	ISO	-	30 dB	-
TEC Current	I_{TEC}	-	0.175 A	-
TEC Voltage	V_{TEC}	-	0.25 V	-
Thermistor Resistance @ 25 °C	R_{TH}	-	10 kΩ	-

a. T_{CASE} = 25 °C; T_{CHIP} = 25 °C.
b. Continuous tuning range between mode hops.
c. As measured with an OSA to empirically determine single frequency range. Laser 30 dB bandwidth and SMSR are subject to monochromator settings and OSA internal algorithms, and will differ from instrument to instrument.
d. Ratio of transmitted light polarized along the fiber's slow axis to transmitted light polarized along the fast axis.

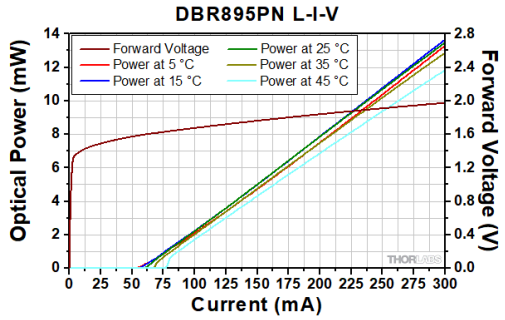


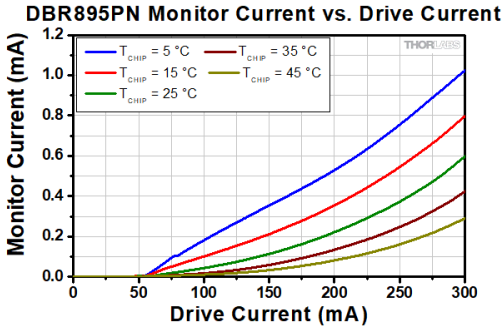
Absolute Max Ratings	
LD Reverse Voltage (Max)	2 V
Laser Current (Max)[a]	See Serialized Datasheet
Laser Power (Max)[a]	See Serialized Datasheet
TEC Current (Max)	3.0 A (T_{CASE} = 20 °C); 2.9 A (T_{CASE} = 70 °C)[b]
TEC Voltage (Max)	3.6 V (T_{CASE} = 20 °C); 4.4 V (T_{CASE} = 70 °C)[b]
PD Reverse Voltage (Max)	15 V
Operating Case Temperature	0 to 50 °C
Operating Chip Temperature	5 to 45 °C
Storage Temperature	-10 to 65 °C

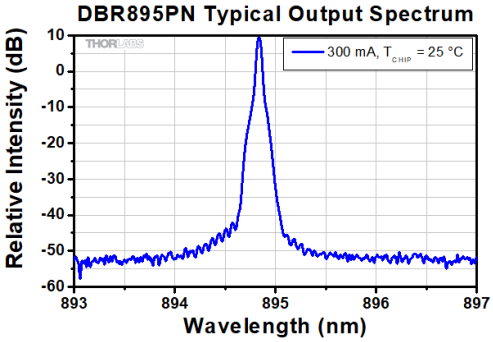
a. Some devices will produce the max laser power before exceeding the typical operating current. Do not drive the laser diode beyond the absolute max laser current or power. Operating in this regime can cause damage to the device.

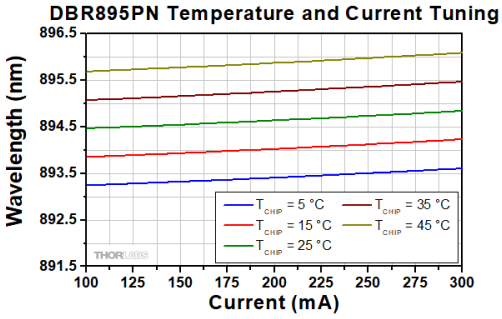
b. Do not operate above maximum operating case temperature. Given for reference purposes only.

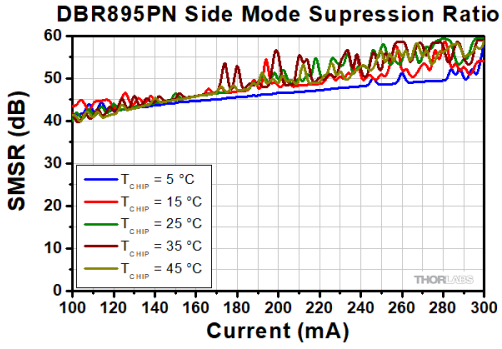
Typical Performance Plots

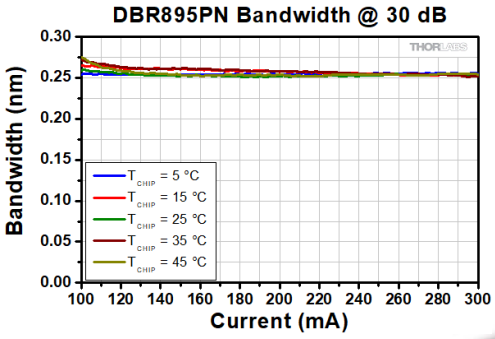




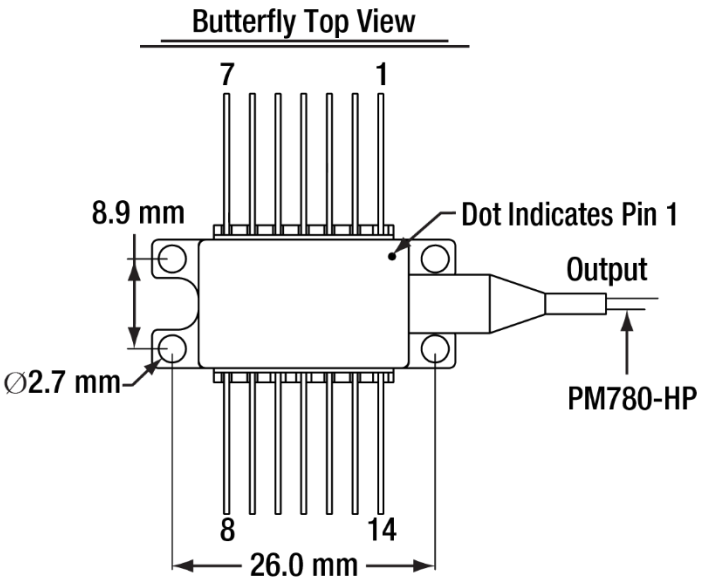








Drawings



PIN IDENTIFICATION			
1.	TEC +	14.	TEC -
2.	Thermistor	13.	Case
3.	PD Anode	12.	NC
4.	PD Cathode	11.	LD Cathode
5.	Thermistor	10.	LD Anode
6.	NC	9.	NC
7.	NC	8.	NC